<u>TOSHIBA</u>

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

2SA1891

Power Amplifier Applications Power Switching Applications

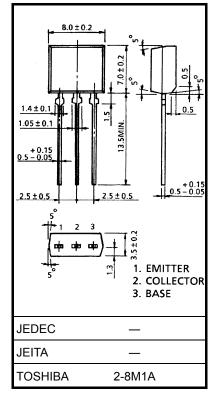
• Low collector-emitter saturation voltage: VCE (sat) = -0.5 V (max)

$$(I_{C} = -1 A)$$

- High collector power dissipation: $P_C = 1.3 \text{ W} (Ta = 25 \text{ °C})$
- High-speed switching time: t_{stg} = 300 ns (typ.)
- Complementary to 2SC5028

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	-60	V	
Collector-emitter voltage		V _{CEO}	-50	V	
Emitter-base voltage		V _{EBO}	-6	V	
Collector current	DC	Ι _C	-2	A	
	Pulse	I _{CP}	-4		
Base current		Ι _Β	-0.2	А	
Collector power dissipation		P _C	1.3	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	



Weight: 0.55 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

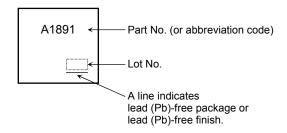
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Unit: mm

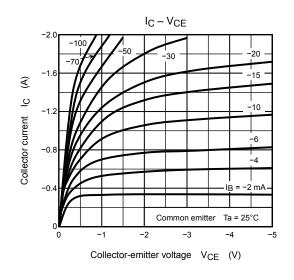
Electrical Characteristics (Ta = 25°C)

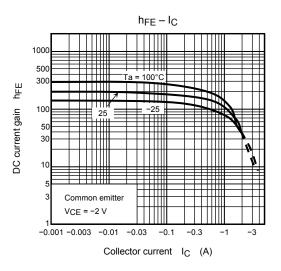
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off c	urrent	I _{CBO}	$V_{CB} = -60 \text{ V}, \text{ I}_{E} = 0$	_	_	-1.0	μA
Emitter cut-off cur	rrent	I _{EBO}	$V_{EB} = -6 V, I_C = 0$		_	-1.0	μA
Collector-emitter	breakdown voltage	V (BR) CEO	I _C = -10 mA, I _B = 0	-50	_	_	V
DC current gain		h _{FE (1)}	$V_{CE} = -2 V, I_C = -100 mA$	120	_	400	
		h _{FE (2)}	V _{CE} = -2 V, I _B = -1.5 A	40	_	_	
Collector-emitter	saturation voltage	V _{CE (sat)}	I _C = -1 A, I _B = -0.05 A		_	-0.5	V
Base-emitter satu	ration voltage	V _{BE (sat)}	I _C = -1 A, I _B = -0.05 A		_	-1.2	V
Transition frequency		fT	$V_{CE} = -2 V, I_C = -100 mA$		100	_	MHz
Collector output capacitance		C _{ob}	V _{CB} = -10 V, I _E = 0, f = 1 MHz		23	_	pF
Switching time Sto	Turn-on time	t _{on}	20 µs Input $\stackrel{IB2}{\longrightarrow}$ $\stackrel{Output}{\longrightarrow}$ $\stackrel{G}{\longrightarrow}$ \stackrel{G}	_	0.1	_	
	Storage time	t _{stg}		_	0.3	_	μs
	Fall time	t _f			0.1	_	

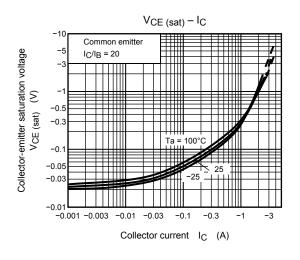
Marking

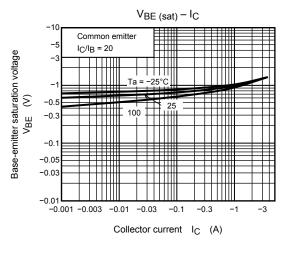


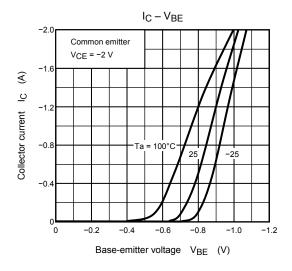
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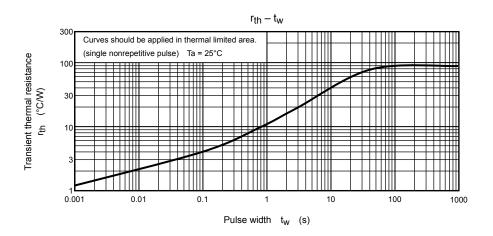


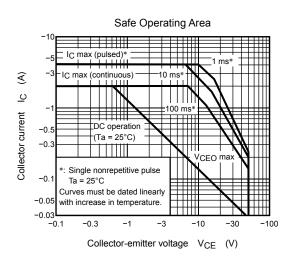


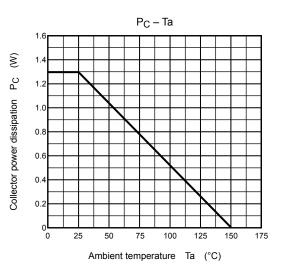












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